Zener Transient Voltage Suppressor SOD-123 Flat Lead Package

The SMF5.0A Series is designed to protect voltage sensitive components from high voltage, high energy transients. Excellent clamping capability, high surge capability, low zener impedance and fast response time. Because of its small size, it is ideal for use in cellular phones, portable devices, business machines, power supplies and many other industrial/consumer applications.

Specification Features:

- Stand–off Voltage: 5 170 Volts
- Peak Power 200 Watts @ 1 ms (SMF5.0A SMF58A)
 175 Watts @ 1 ms (SMF60A SMF170A)
- Maximum Clamp Voltage @ Peak Pulse Current
- Low Leakage
- Response Time is Typically < 1 ns
- ESD Rating of Class 3 (> 16 kV) per Human Body Model IEC61000-4-2 Level 4 ESD Protection IEC61000-4-4 40 A ESD Protection
- Low Profile Maximum Height of 1.0 mm
- Small Footprint Footprint Area of 8.45 mm²
- Supplied in 8 mm Tape and Reel 3,000 Units per Reel
- Cathode Indicated by Polarity Band

Mechanical Characteristics:

CASE: Void-free, transfer-molded, thermosetting plastic Epoxy Meets UL94, VO LEAD FINISH: 100% Matte Sn (Tin) MOUNTING POSITION: Any QUALIFIED MAX REFLOW TEMPERATURE: 260°C Device Meets MSL 1 Requirements



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PLASTIC SURFACE MOUNT ZENER OVERVOLTAGE TRANSIENT SUPPRESSOR 5 – 170 VOLTS 200 WATT PEAK POWER





SOD-123FL CASE 498 PLASTIC

MARKING DIAGRAM



XX = Specific Device Code D = Date Code

ORDERING INFORMATION

| Device | Package | Shipping | | |
|-----------|-----------|-------------------|--|--|
| SMFxxxAT1 | SOD-123FL | 3,000/Tape & Reel | | |

LEAD ORIENTATION IN TAPE:

Cathode Lead to Sprocket Holes

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--|------------------------------------|-------------------|---------------------|
| Maximum P_{pk} Dissipation (PW–10/1000 μ s) (Note 1) SMF60A – SMF170A | P _{pk} | 175 | W |
| Maximum P_{pk} Dissipation (PW–10/1000 μ s) (Note 1) SMF5.0A – SMF58A | P _{pk} | 200 | W |
| Maximum P_{pk} Dissipation @ $T_A = 25^{\circ}C$, (PW-8/20 µs) (Note 2) | P _{pk} | 1000 | W |
| DC Power Dissipation @ T _A = 25°C (Note 3) Derate above 25°C Thermal Resistance from Junction to Ambient (Note 3) | P _D R _{θJA} | 385 4.0 325 | mW mW/°C °C/W |
| Thermal Resistance from Junction to Lead (Note 3) | $R_{\theta J cathode}$ | 26 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{stg} | -55 to +150 | °C |

1. Non-repetitive current pulse at $T_A = 25^{\circ}C$, per waveform of Figure 2. 2. Non-repetitive current pulse at $T_A = 25^{\circ}C$, per waveform of Figure 3. 3. Mounted with recommended minimum pad size, DC board FR-4.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted, V_F = 3.5 V Max. @ I_F (Note 4) = 12 A)

| Symbol | Parameter | | | | | | |
|------------------|--|--|--|--|--|--|--|
| Symbol | Falailletei | | | | | | |
| I _{PP} | Maximum Reverse Peak Pulse Current | | | | | | |
| V _C | Clamping Voltage @ IPP | | | | | | |
| V _{RWM} | Working Peak Reverse Voltage | | | | | | |
| I _R | Maximum Reverse Leakage Current @ V _{RWM} | | | | | | |
| V _{BR} | Breakdown Voltage @ I _T | | | | | | |
| Ι _Τ | Test Current | | | | | | |
| ١ _F | Forward Current | | | | | | |
| VF | Forward Voltage @ I _F | | | | | | |

4. 1/2 sine wave (or equivalent square wave), PW = 8.3 ms, duty cycle = 4 pulses per minute maximum.



| ELECTRICAL CHARACTERISTICS | $(T_L = 30^{\circ}C \text{ unless otherwise noted}, V_F = 1.25 \text{ Volts } @ 200 \text{ mA})$ |
|----------------------------|--|
|----------------------------|--|

| | | V _{RWM} (V) V _{BR} @ h (V) (Ne | | | ote 6) I _T | | I _R @ V _{RWM} | V _{C(Max)} | I _{PP(Max)} (A) |
|---------|---------|---|------|-------|-----------------------|------|-----------------------------------|---------------------|--------------------------|
| Device | Marking | (Note 5) | Min | Nom | Max | (mA) | (μΑ) | (V) | (Note 7) |
| SMF5.0A | KE | 5 | 6.4 | 6.7 | 7 | 10 | 400 | 9.2 | 21.7 |
| SMF6.0A | KG | 6 | 6.67 | 7.02 | 7.37 | 10 | 400 | 10.3 | 19.4 |
| SMF6.5A | KK | 6.5 | 7.22 | 7.6 | 7.98 | 10 | 250 | 11.2 | 17.9 |
| SMF7.0A | KM | 7 | 7.78 | 8.2 | 8.6 | 10 | 100 | 12 | 16.7 |
| SMF7.5A | KP | 7.5 | 8.33 | 8.77 | 9.21 | 1 | 50 | 12.9 | 15.5 |
| SMF8.0A | KR | 8 | 8.89 | 9.36 | 9.83 | 1 | 25 | 13.6 | 14.7 |
| SMF8.5A | KT | 8.5 | 9.44 | 9.92 | 10.4 | 1 | 10 | 14.4 | 13.9 |
| SMF9.0A | KV | 9 | 10 | 10.55 | 11.1 | 1 | 5 | 15.4 | 13.0 |
| SMF10A | КХ | 10 | 11.1 | 11.7 | 12.3 | 1 | 2.5 | 17 | 11.8 |
| SMF11A | KZ | 11 | 12.2 | 12.85 | 13.5 | 1 | 2.5 | 18.2 | 11.0 |
| SMF12A | LE | 12 | 13.3 | 14 | 14.7 | 1 | 2.5 | 19.9 | 10.1 |
| SMF13A | LG | 13 | 14.4 | 15.15 | 15.9 | 1 | 1 | 21.5 | 9.3 |
| SMF14A | LK | 14 | 15.6 | 16.4 | 17.2 | 1 | 1 | 23.2 | 8.6 |
| SMF15A | LM | 15 | 16.7 | 17.6 | 18.5 | 1 | 1 | 24.4 | 8.2 |
| SMF16A | LP | 16 | 17.8 | 18.75 | 19.7 | 1 | 1 | 26 | 7.7 |
| SMF17A | LR | 17 | 18.9 | 19.9 | 20.9 | 1 | 1 | 27.6 | 7.2 |
| SMF18A | LT | 18 | 20 | 21 | 22.1 | 1 | 1 | 29.2 | 6.8 |
| SMF20A | LV | 20 | 22.2 | 23.35 | 24.5 | 1 | 1 | 32.4 | 6.2 |
| SMF22A | LX | 22 | 24.4 | 25.6 | 26.9 | 1 | 1 | 35.5 | 5.6 |
| SMF24A | LZ | 24 | 26.7 | 28.1 | 29.5 | 1 | 1 | 38.9 | 5.1 |
| SMF26A | ME | 26 | 28.9 | 30.4 | 31.9 | 1 | 1 | 42.1 | 4.8 |
| SMF28A | MG | 28 | 31.1 | 32.8 | 34.4 | 1 | 1 | 45.4 | 4.4 |
| SMF30A | MK | 30 | 33.3 | 35.1 | 36.8 | 1 | 1 | 48.4 | 4.1 |
| SMF33A | MM | 33 | 36.7 | 38.7 | 40.6 | 1 | 1 | 53.3 | 3.8 |
| SMF36A | MP | 36 | 40 | 42.1 | 44.2 | 1 | 1 | 58.1 | 3.4 |
| SMF40A | MR | 40 | 44.4 | 46.8 | 49.1 | 1 | 1 | 64.5 | 3.1 |
| SMF43A | MT | 43 | 47.8 | 50.3 | 52.8 | 1 | 1 | 69.4 | 2.9 |
| SMF45A | MV | 45 | 50 | 52.65 | 55.3 | 1 | 1 | 72.7 | 2.8 |
| SMF48A | MX | 48 | 53.3 | 56.1 | 58.9 | 1 | 1 | 77.4 | 2.6 |
| SMF51A | MZ | 51 | 56.7 | 59.7 | 62.7 | 1 | 1 | 82.4 | 2.4 |
| SMF54A | NE | 54 | 60 | 63.15 | 66.3 | 1 | 1 | 87.1 | 2.3 |
| SMF58A | NG | 58 | 64.4 | 67.8 | 71.2 | 1 | 1 | 93.6 | 2.1 |
| SMF60A | NK | 60 | 66.7 | 70.2 | 73.7 | 1 | 1 | 96.8 | 1.8 |
| SMF64A | NM | 64 | 71.1 | 74.85 | 78.6 | 1 | 1 | 103 | 1.7 |
| SMF70A | NP | 70 | 77.8 | 81.9 | 86 | 1 | 1 | 113 | 1.5 |
| SMF75A | NR | 75 | 83.3 | 87.7 | 92.1 | 1 | 1 | 121 | 1.4 |
| SMF78A | NT | 78 | 86.7 | 91.25 | 95.8 | 1 | 1 | 126 | 1.4 |
| SMF85A | NV | 85 | 94.4 | 99.2 | 104 | 1 | 1 | 137 | 1.3 |
| SMF90A | NX | 90 | 100 | 105.5 | 111 | 1 | 1 | 146 | 1.2 |
| SMF100A | NZ | 100 | 111 | 117 | 123 | 1 | 1 | 162 | 1.1 |
| SMF110A | PE | 110 | 122 | 128.5 | 135 | 1 | 1 | 177 | 1.0 |
| SMF120A | PG | 120 | 133 | 140 | 147 | 1 | 1 | 193 | 0.9 |
| SMF130A | PK | 130 | 144 | 151.5 | 159 | 1 | 1 | 209 | 0.8 |
| SMF150A | PM | 150 | 167 | 176 | 185 | 1 | 1 | 243 | 0.7 |
| SMF160A | PP | 160 | 178 | 187.5 | 197 | 1 | 1 | 259 | 0.7 |
| SMF170A | PR | 170 | 189 | 199 | 209 | 1 | 1 | 275 | 0.6 |

A transient suppressor is normally selected according to the Working Peak Reverse Voltage (V_{RWM}) which should be equal to or greater than the DC or continuous peak operating voltage level.
 V_{BR} measured at pulse test current I_T at ambient temperature of 25°C.
 Surge current waveform per Figure 2 and derate per Figure 3.

TYPICAL PROTECTION CIRCUIT





Figure 5. Typical Derating Factor for Duty Cycle





INFORMATION FOR USING THE SOD-123 FLAT LEAD SURFACE MOUNT PACKAGE

MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.

RECOMMENDED FOOTPRINT FOR SOD-123FL



POWERMITE POWER DISSIPATION

The power dissipation of the SOD–123 Flat Lead is a function of the mounting pad size. This can vary from the minimum pad size for soldering to a pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by $T_{J(max)}$, the maximum rated junction temperature of the die, $R_{\theta JA}$, the thermal resistance from the device junction to ambient, and the operating temperature, T_A . Using the values provided on the data sheet for the SOD–123 Flat Lead package, P_D can be calculated as follows:

$$P_{D} = \frac{T_{J(max)} - T_{A}}{R_{\theta JA}}$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values into the equation for an ambient temperature T_A of 25°C,

SOLDERING PRECAUTIONS

The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference shall be a maximum of 10°C.

one can calculate the power dissipation of the device which in this case is 385 milliwatts.

$$P_{D} = \frac{150^{\circ}C - 25^{\circ}C}{325^{\circ}C/W} = 385 \text{ milliwatts}$$

The 325°C/W for the SOD–123 Flat Lead package assumes the use of the recommended footprint on a glass epoxy printed circuit board to achieve a power dissipation of 385 milliwatts. There are other alternatives to achieving higher power dissipation from the SOD–123 Flat Lead package. Another alternative would be to use a ceramic substrate or an aluminum core board such as Thermal Clad[®]. Using a board material such as Thermal Clad, an aluminum core board, the power dissipation can be doubled using the same footprint.

PERING PRECAUTIONS

- The soldering temperature and time shall not exceed 260°C for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient shall be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes. Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling.

* Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.

OUTLINE DIMENSIONS

Transient Voltage Suppressor – Surface Mounted

SOD-123FL

200 Watt Peak Power





NOTES:

- IDIES:
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH.
 DIMENSIONS D AND J ARE TO BE MEASURED ON FLAT SECTION OF THE LEAD; BETWEEN 0.10 AND 0.25 MM FROM THE LEAD TIP.

| | MILLIN | IETERS | INCHES | | |
|-----|--------|---------------|--------|-------|--|
| DIM | MIN | MIN MAX MIN M | | MAX | |
| Α | 1.50 | 1.80 | 0.059 | 0.071 | |
| В | 2.50 | 2.90 | 0.098 | 0.114 | |
| С | 0.90 | 1.00 | 0.035 | 0.039 | |
| D | 0.70 | 1.10 | 0.028 | 0.043 | |
| Е | 0.55 | 0.95 | 0.022 | 0.037 | |
| Η | 0.00 | 0.10 | 0.000 | 0.004 | |
| J | 0.10 | 0.20 | 0.004 | 0.008 | |
| K | 3.40 | 3.80 | 0.134 | 0.150 | |
| L | 0 ° | 8 ° | 0 ° | 8 ° | |

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